Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.405 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak

Current Rating Per Characteristic:

1.00 amperes source cutoff current preset and 15.00 microamperes forward current, average peak

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

Special Features:

Item must comply with rqmt of desc production standard no.L02664; for navy nuclear propulsion plant products only

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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